

# CD4006BMS

December 1992

## CMOS 18-Stage Static Register

### Features

- High-Voltage Type (20V Rating)
- Fully Static Operation
- Shifting Rates Up to 12MHz at 10V (typ)
- Permanent Register Storage with Clock Line High or Low - No Information Recirculation Required
- 100% Tested for Quiescent Current at 20V
- Standardized, Symmetrical Output Characteristics
- 5V, 10V and 15V Parametric Ratings
- Maximum Input Current of  $1\mu A$  at 18V Over Full Package-Temperature Range; 100nA at 18V and  $+25^\circ C$
- Noise Margin (Full Package-Temperature Range):
  - 1V at  $VDD = 5V$
  - 2V at  $VDD = 10V$
  - 2.5V at  $VDD = 15V$
- Meets All Requirements of JEDEC Tentative Standards No. 13B, "Standard Specifications for Description of "B" Series CMOS Devices"

### Applications

- Serial Shift Registers
- Frequency Division
- Time Delay Circuits

### Description

CD4006BMS types are composed of 4 separate shift register sections: two sections of four stages and two sections of five stages with an output tap at the fourth stage. Each section has an independent single-rail data path.

A common clock signal is used for all stages. Data are shifted to the next stages on negative-going transitions of the clock. Through appropriate connections of inputs and outputs, multiple register sections of 4, 5, 8, and 9 stages or single register sections of 10, 12, 13, 14, 16, 17 and 18 stages can be implemented using one CD4006BMS package. Longer shift register sections can be assembled by using more than one CD4006BMS.

To facilitate cascading stages when clock rise and fall times are slow, an optional output ( $D1 + 4'$ ) that is delayed one-half clock-cycle, is provided (see Truth Table for Output from Term. 2).

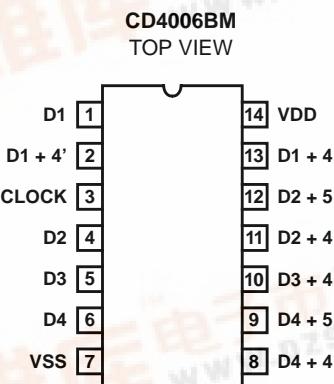
The CD4006BMS is supplied in these 14 lead outline packages:

Braze Seal DIP H4Q

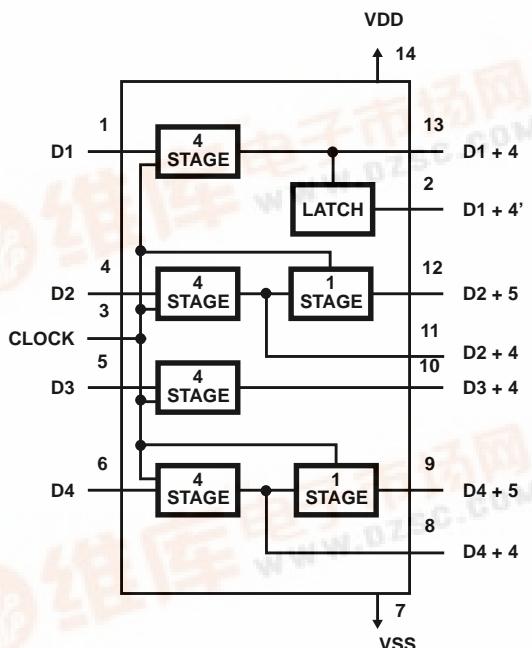
Frit Seal DIP H6D

Ceramic Flatpack H4F

### Pinout



### Functional Diagram



## Specifications CD4006BMS

| Absolute Maximum Ratings                      |   | Reliability Information   |   |               |  |
|---|---|---|---|---------------|--|
| DC Supply Voltage Range, (VDD) . . . . .      | -0.5V to +20V<br>(Voltage Referenced to VSS Terminals)                                |   | $\theta_{ja}$                           | $\theta_{jc}$ |  |
| Input Voltage Range, All Inputs . . . . .     | -0.5V to VDD +0.5V  | Ceramic DIP and FRIT Package . . . . .  | 80°C/W                                  | 20°C/W        |  |
| DC Input Current, Any One Input . . . . .     | $\pm 10\text{mA}$   | Flatpack Package . . . . .  | 70°C/W                                  | 20°C/W        |  |
| Operating Temperature Range . . . . .         | -55°C to +125°C<br>Package Types D, F, K, H   | Maximum Package Power Dissipation (PD) at +125°C<br>For TA = -55°C to +100°C (Package Type D, F, K) . . . . . | 500mW                                   |               |  |
| Storage Temperature Range (TSTG) . . . . .    | -65°C to +150°C   | For TA = +100°C to +125°C (Package Type D, F, K) . . . . .  | Derate<br>Linearity at 12mW/°C to 200mW |               |  |
| Lead Temperature (During Soldering) . . . . . | +265°C<br>At Distance 1/16 ± 1/32 Inch (1.59mm ± 0.79mm) from case for<br>10s Maximum | Device Dissipation per Output Transistor . . . . .  | 100mW                                   |               |  |
|   |   | For TA = Full Package Temperature Range (All Package Types)   |   |               |  |
|   |   | Junction Temperature . . . . .  | +175°C                                  |               |  |

TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS

| PARAMETER                      | SYMBOL | CONDITIONS (NOTE 1)                   | GROUP A<br>SUBGROUPS | TEMPERATURE          | LIMITS      |             | UNITS |
|--------------------------------|--------|---------------------------------------|----------------------|----------------------|-------------|-------------|-------|
|                                |        |                                       |                      |                      | MIN         | MAX         |       |
| Supply Current                 | IDD    | VDD = 20V, VIN = VDD or GND           | 1                    | +25°C                | -           | 10          | µA    |
|                                |        |                                       | 2                    | +125°C               | -           | 1000        | µA    |
|                                |        | VDD = 18V, VIN = VDD or GND           | 3                    | -55°C                | -           | 10          | µA    |
| Input Leakage Current          | IIL    | VIN = VDD or GND                      | 1                    | +25°C                | -100        | -           | nA    |
|                                |        |                                       | 2                    | +125°C               | -1000       | -           | nA    |
|                                |        | VDD = 18V                             | 3                    | -55°C                | -100        | -           | nA    |
| Input Leakage Current          | IIH    | VIN = VDD or GND                      | 1                    | +25°C                | -           | 100         | nA    |
|                                |        |                                       | 2                    | +125°C               | -           | 1000        | nA    |
|                                |        | VDD = 18V                             | 3                    | -55°C                | -           | 100         | nA    |
| Output Voltage                 | VOL15  | VDD = 15V, No Load                    | 1, 2, 3              | +25°C, +125°C, -55°C | -           | 50          | mV    |
| Output Voltage                 | VOH15  | VDD = 15V, No Load (Note 3)           | 1, 2, 3              | +25°C, +125°C, -55°C | 14.95       | -           | V     |
| Output Current (Sink)          | IOL5   | VDD = 5V, VOUT = 0.4V                 | 1                    | +25°C                | 0.53        | -           | mA    |
| Output Current (Sink)          | IOL10  | VDD = 10V, VOUT = 0.5V                | 1                    | +25°C                | 1.4         | -           | mA    |
| Output Current (Sink)          | IOL15  | VDD = 15V, VOUT = 1.5V                | 1                    | +25°C                | 3.5         | -           | mA    |
| Output Current (Source)        | IOH5A  | VDD = 5V, VOUT = 4.6V                 | 1                    | +25°C                | -           | -0.53       | mA    |
| Output Current (Source)        | IOH5B  | VDD = 5V, VOUT = 2.5V                 | 1                    | +25°C                | -           | -1.8        | mA    |
| Output Current (Source)        | IOH10  | VDD = 10V, VOUT = 9.5V                | 1                    | +25°C                | -           | -1.4        | mA    |
| Output Current (Source)        | IOH15  | VDD = 15V, VOUT = 13.5V               | 1                    | +25°C                | -           | -3.5        | mA    |
| N Threshold Voltage            | VNTH   | VDD = 10V, ISS = -10µA                | 1                    | +25°C                | -2.8        | -0.7        | V     |
| P Threshold Voltage            | VPTH   | VSS = 0V, IDD = 10µA                  | 1                    | +25°C                | 0.7         | 2.8         | V     |
| Functional                     | F      | VDD = 2.8V, VIN = VDD or GND          | 7                    | +25°C                | VOH > VDD/2 | VOL < VDD/2 | V     |
|                                |        | VDD = 20V, VIN = VDD or GND           | 7                    | +25°C                |             |             |       |
|                                |        | VDD = 18V, VIN = VDD or GND           | 8A                   | +125°C               |             |             |       |
|                                |        | VDD = 3V, VIN = VDD or GND            | 8B                   | -55°C                |             |             |       |
| Input Voltage Low<br>(Note 2)  | VIL    | VDD = 5V, VOH > 4.5V, VOL < 0.5V      | 1, 2, 3              | +25°C, +125°C, -55°C | -           | 1.5         | V     |
| Input Voltage High<br>(Note 2) | VIH    | VDD = 5V, VOH > 4.5V, VOL < 0.5V      | 1, 2, 3              | +25°C, +125°C, -55°C | 3.5         | -           | V     |
| Input Voltage Low<br>(Note 2)  | VIL    | VDD = 15V, VOH > 13.5V,<br>VOL < 1.5V | 1, 2, 3              | +25°C, +125°C, -55°C | -           | 4           | V     |
| Input Voltage High<br>(Note 2) | VIH    | VDD = 15V, VOH > 13.5V,<br>VOL < 1.5V | 1, 2, 3              | +25°C, +125°C, -55°C | 11          | -           | V     |

NOTES: 1. All voltages referenced to device GND, 100% testing being implemented.

3. For accuracy, voltage is measured differentially to VDD. Limit is 0.050V max.

2. Go/No Go test with limits applied to inputs

## Specifications CD4006BMS

**TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS**

| PARAMETER                     | SYMBOL       | CONDITIONS (NOTE 1, 2)     | GROUP A<br>SUBGROUPS | TEMPERATURE   | LIMITS |     | UNITS |
|-------------------------------|--------------|----------------------------|----------------------|---------------|--------|-----|-------|
|                               |              |                            |                      |               | MIN    | MAX |       |
| Propagation Delay             | TPHL<br>TPLH | VDD = 5V, VIN = VDD or GND | 9                    | +25°C         | -      | 400 | ns    |
|                               |              |                            | 10, 11               | +125°C, -55°C | -      | 540 | ns    |
| Transition Time               | TTHL<br>TTLH | VDD = 5V, VIN = VDD or GND | 9                    | +25°C         | -      | 200 | ns    |
|                               |              |                            | 10, 11               | +125°C, -55°C | -      | 270 | ns    |
| Maximum Clock Input Frequency | FCL          | VDD = 5V                   | 9                    | +25°C         | 2.5    | -   | MHz   |
|                               |              | VIN = VDD or GND           | 10, 11               | +125°C, -55°C | 1.85   | -   | MHz   |

NOTES:

1. CL = 50pF, RL = 200K, Input TR, TF < 20ns.
2. 55°C and +125°C limits guaranteed, 100% testing being implemented.

**TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS**

| PARAMETER               | SYMBOL | CONDITIONS                    | NOTES | TEMPERATURE             | LIMITS |       | UNITS |
|-------------------------|--------|-------------------------------|-------|-------------------------|--------|-------|-------|
|                         |        |                               |       |                         | MIN    | MAX   |       |
| Supply Current          | IDD    | VDD = 5V, VIN = VDD or GND    | 1, 2  | -55°C, +25°C            | -      | 5     | µA    |
|                         |        |                               |       | +125°C                  | -      | 150   | µA    |
|                         |        | VDD = 10V, VIN = VDD or GND   | 1, 2  | -55°C, +25°C            | -      | 10    | µA    |
|                         |        |                               |       | +125°C                  | -      | 300   | µA    |
|                         |        | VDD = 15V, VIN = VDD or GND   | 1, 2  | -55°C, +25°C            | -      | 10    | µA    |
|                         |        |                               |       | +125°C                  | -      | 600   | µA    |
| Output Voltage          | VOL    | VDD = 5V, No Load             | 1, 2  | +25°C, +125°C,<br>-55°C | -      | 50    | mV    |
| Output Voltage          | VOL    | VDD = 10V, No Load            | 1, 2  | +25°C, +125°C,<br>-55°C | -      | 50    | mV    |
| Output Voltage          | VOH    | VDD = 5V, No Load             | 1, 2  | +25°C, +125°C,<br>-55°C | 4.95   | -     | V     |
| Output Voltage          | VOH    | VDD = 10V, No Load            | 1, 2  | +25°C, +125°C,<br>-55°C | 9.95   | -     | V     |
| Output Current (Sink)   | IOL5   | VDD = 5V, VOUT = 0.4V         | 1, 2  | +125°C                  | 0.36   | -     | mA    |
|                         |        |                               |       | -55°C                   | 0.64   | -     | mA    |
| Output Current (Sink)   | IOL10  | VDD = 10V, VOUT = 0.5V        | 1, 2  | +125°C                  | 0.9    | -     | mA    |
|                         |        |                               |       | -55°C                   | 1.6    | -     | mA    |
| Output Current (Sink)   | IOL15  | VDD = 15V, VOUT = 1.5V        | 1, 2  | +125°C                  | 2.4    | -     | mA    |
|                         |        |                               |       | -55°C                   | 4.2    | -     | mA    |
| Output Current (Source) | IOH5A  | VDD = 5V, VOUT = 4.6V         | 1, 2  | +125°C                  | -      | -0.36 | mA    |
|                         |        |                               |       | -55°C                   | -      | -0.64 | mA    |
| Output Current (Source) | IOH5B  | VDD = 5V, VOUT = 2.5V         | 1, 2  | +125°C                  | -      | -1.15 | mA    |
|                         |        |                               |       | -55°C                   | -      | -2.0  | mA    |
| Output Current (Source) | IOH10  | VDD = 10V, VOUT = 9.5V        | 1, 2  | +125°C                  | -      | -0.9  | mA    |
|                         |        |                               |       | -55°C                   | -      | -1.6  | mA    |
| Output Current (Source) | IOH15  | VDD = 15V, VOUT = 13.5V       | 1, 2  | +125°C                  | -      | -2.4  | mA    |
|                         |        |                               |       | -55°C                   | -      | -4.2  | mA    |
| Input Voltage Low       | VIL    | VDD = 10V, VOH > 9V, VOL < 1V | 1, 2  | +25°C, +125°C,<br>-55°C | -      | 3     | V     |
| Input Voltage High      | VIH    | VDD = 10V, VOH > 9V, VOL < 1V | 1, 2  | +25°C, +125°C,<br>-55°C | +7     | -     | V     |

## Specifications CD4006BMS

**TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)**

| PARAMETER                     | SYMBOL       | CONDITIONS | NOTES   | TEMPERATURE | LIMITS |     | UNITS |
|-------------------------------|--------------|------------|---------|-------------|--------|-----|-------|
|                               |              |            |         |             | MIN    | MAX |       |
| Propagation Delay             | TPHL<br>TPLH | VDD = 10V  | 1, 2, 3 | +25°C       | -      | 200 | ns    |
|                               |              | VDD = 15V  | 1, 2, 3 | +25°C       | -      | 160 | ns    |
| Transition Time               | TTHL<br>TTLH | VDD = 10V  | 1, 2, 3 | +25°C       | -      | 100 | ns    |
|                               |              | VDD = 15V  | 1, 2, 3 | +25°C       | -      | 80  | ns    |
| Maximum Clock Input Frequency | FCL          | VDD = 10V  | 1, 2, 3 | +25°C       | 5      | -   | MHz   |
|                               |              | VDD = 15V  | 1, 2, 3 | +25°C       | 7      | -   | MHz   |
| Minimum Data Setup Time       | TS           | VDD = 5V   | 1, 2, 3 | +25°C       | -      | 100 | ns    |
|                               |              | VDD = 10V  | 1, 2, 3 | +25°C       | -      | 50  | ns    |
|                               |              | VDD = 15V  | 1, 2, 3 | +25°C       | -      | 40  | ns    |
| Minimum Clock Pulse Width     | TW           | VDD = 5V   | 1, 2, 3 | +25°C       | -      | 180 | ns    |
|                               |              | VDD = 10V  | 1, 2, 3 | +25°C       | -      | 80  | ns    |
|                               |              | VDD = 15V  | 1, 2, 3 | +25°C       | -      | 50  | ns    |
| Input Capacitance             | CIN          | Any Input  | 1, 2    | +25°C       | -      | 7.5 | pF    |

NOTES:

1. All voltages referenced to device GND.
2. The parameters listed on Table 3 are controlled via design or process and are not directly tested. These parameters are characterized on initial design release and upon design changes which would affect these characteristics.
3. CL = 50pF, RL = 200K, Input TR, TF < 20ns.

**TABLE 4. POST IRRADIATION ELECTRICAL PERFORMANCE CHARACTERISTICS**

| PARAMETER                 | SYMBOL       | CONDITIONS                  | NOTES | TEMPERATURE | LIMITS      |             | UNITS |
|---------------------------|--------------|-----------------------------|-------|-------------|-------------|-------------|-------|
|                           |              |                             |       |             | MIN         | MAX         |       |
| Supply Current            | IDD          | VDD = 20V, VIN = VDD or GND | 1, 4  | +25°C       | -           | 25          | µA    |
| N Threshold Voltage       | VNTH         | VDD = 10V, ISS = -10µA      | 1, 4  | +25°C       | -2.8        | -0.2        | V     |
| N Threshold Voltage Delta | ΔVNTH        | VDD = 10V, ISS = -10µA      | 1, 4  | +25°C       | -           | ±1          | V     |
| P Threshold Voltage       | VPTH         | VSS = 0V, IDD = 10µA        | 1, 4  | +25°C       | 0.2         | 2.8         | V     |
| P Threshold Voltage Delta | ΔVPTH        | VSS = 0V, IDD = 10µA        | 1, 4  | +25°C       | -           | ±1          | V     |
| Functional                | F            | VDD = 18V, VIN = VDD or GND | 1     | +25°C       | VOH > VDD/2 | VOL < VDD/2 | V     |
| Propagation Delay Time    | TPHL<br>TPLH | VDD = 5V                    |       |             |             |             |       |

NOTES: 1. All voltages referenced to device GND.

3. See Table 2 for +25°C limit.

2. CL = 50pF, RL = 200K, Input TR, TF < 20ns.

4. Read and Record

**TABLE 5. BURN-IN AND LIFE TEST DELTA PARAMETERS +25°C**

| PARAMETER               | SYMBOL | DELTA LIMIT              |
|-------------------------|--------|--------------------------|
| Supply Current - MSI-2  | IDD    | ± 1.0µA                  |
| Output Current (Sink)   | IOL5   | ± 20% x Pre-Test Reading |
| Output Current (Source) | IOH5A  | ± 20% x Pre-Test Reading |

## **Specifications CD4006BMS**

**TABLE 6. APPLICABLE SUBGROUPS**

| <b>CONFORMANCE GROUP</b>      | <b>MIL-STD-883<br/>METHOD</b> | <b>GROUP A SUBGROUPS</b>      | <b>READ AND RECORD</b>                |
|-------------------------------|-------------------------------|-------------------------------|---------------------------------------|
| Initial Test (Pre Burn-In)    | 100% 5004                     | 1, 7, 9                       | IDD, IOL5, IOH5A                      |
| Interim Test 1 (Post Burn-In) | 100% 5004                     | 1, 7, 9                       | IDD, IOL5, IOH5A                      |
| Interim Test 2 (Post Burn-In) | 100% 5004                     | 1, 7, 9                       | IDD, IOL5, IOH5A                      |
| PDA (Note 1)                  | 100% 5004                     | 1, 7, 9, Deltas               |                                       |
| Interim Test 3 (Post Burn-In) | 100% 5004                     | 1, 7, 9                       | IDD, IOL5, IOH5A                      |
| PDA (Note 1)                  | 100% 5004                     | 1, 7, 9, Deltas               |                                       |
| Final Test                    | 100% 5004                     | 2, 3, 8A, 8B, 10, 11          |                                       |
| Group A                       | Sample 5005                   | 1, 2, 3, 7, 8A, 8B, 9, 10, 11 |                                       |
| Group B                       | Subgroup B-5                  | Sample 5005                   | 1, 2, 3, 7, 8A, 8B, 9, 10, 11, Deltas |
|                               | Subgroup B-6                  | Sample 5005                   | 1, 7, 9                               |
| Group D                       | Sample 5005                   | 1, 2, 3, 8A, 8B, 9            | Subgroups 1, 2 3                      |

NOTE: 1. 5% Parameteric, 3% Functional; Cumulative for Static 1 and 2.

**TABLE 7. TOTAL DOSE IRRADIATION**

| <b>CONFORMANCE GROUPS</b> | <b>MIL-STD-883<br/>METHOD</b> | <b>TEST</b>      |                   | <b>READ AND RECORD</b> |                   |
|---------------------------|-------------------------------|------------------|-------------------|------------------------|-------------------|
|                           |                               | <b>PRE-IRRAD</b> | <b>POST-IRRAD</b> | <b>PRE-IRRAD</b>       | <b>POST-IRRAD</b> |
| Group E Subgroup 2        | 5005                          | 1, 7, 9          | Table 4           | 1, 9                   | Table 4           |

**TABLE 8. BURN-IN AND IRRADIATION TEST CONNECTIONS**

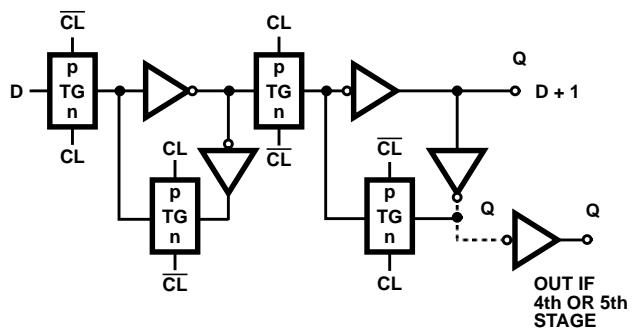
| <b>FUNCTION</b>            | <b>OPEN</b> | <b>GROUND</b> | <b>VDD</b>   | <b>9V ± -0.5V</b> | <b>OSCILLATOR</b> |              |
|----------------------------|-------------|---------------|--------------|-------------------|-------------------|--------------|
|                            |             |               |              |                   | <b>50kHz</b>      | <b>25kHz</b> |
| Static Burn-In 1<br>Note 1 | 2, 8 - 13   | 1, 3 - 7      | 14           |                   |                   |              |
| Static Burn-In 2<br>Note 1 | 2, 8 - 13   | 7             | 1, 3 - 6, 14 |                   |                   |              |
| Dynamic Burn-In Note 1     | 2           | 7             | 14           | 8 - 13            | 3                 | 1, 4 - 6     |
| Irradiation<br>Note 2      | 2, 8 - 13   | 7             | 1, 3 - 6, 14 |                   |                   |              |

NOTE:

1. Each pin except VDD and GND will have a series resistor of  $10K \pm 5\%$ ,  $VDD = 18V \pm 0.5V$
2. Each pin except VDD and GND will have a series resistor of  $47K \pm 5\%$ ; Group E, Subgroup 2, sample size is 4 dice/wafer, 0 failures,  $VDD = 10V \pm 0.5V$

## CD4006BMS

### Logic Diagram and Truth Table



LOGIC DIAGRAM AND TRUTH TABLE (ONE REGISTER STAGE)

TRUTH TABLE FOR SHIFT REGISTER STAGE

| D | CL* | D + 1 |
|---|-----|-------|
| 0 | —   | 0     |
| 1 | —   | 1     |
| X | —   | NC    |

TRUTH TABLE FOR OUTPUT FROM TERM 2

| D1 + 4 | CL* | D1 + 4' |
|--------|-----|---------|
| 0      | —   | 0       |
| 1      | —   | 1       |
| X      | —   | NC      |

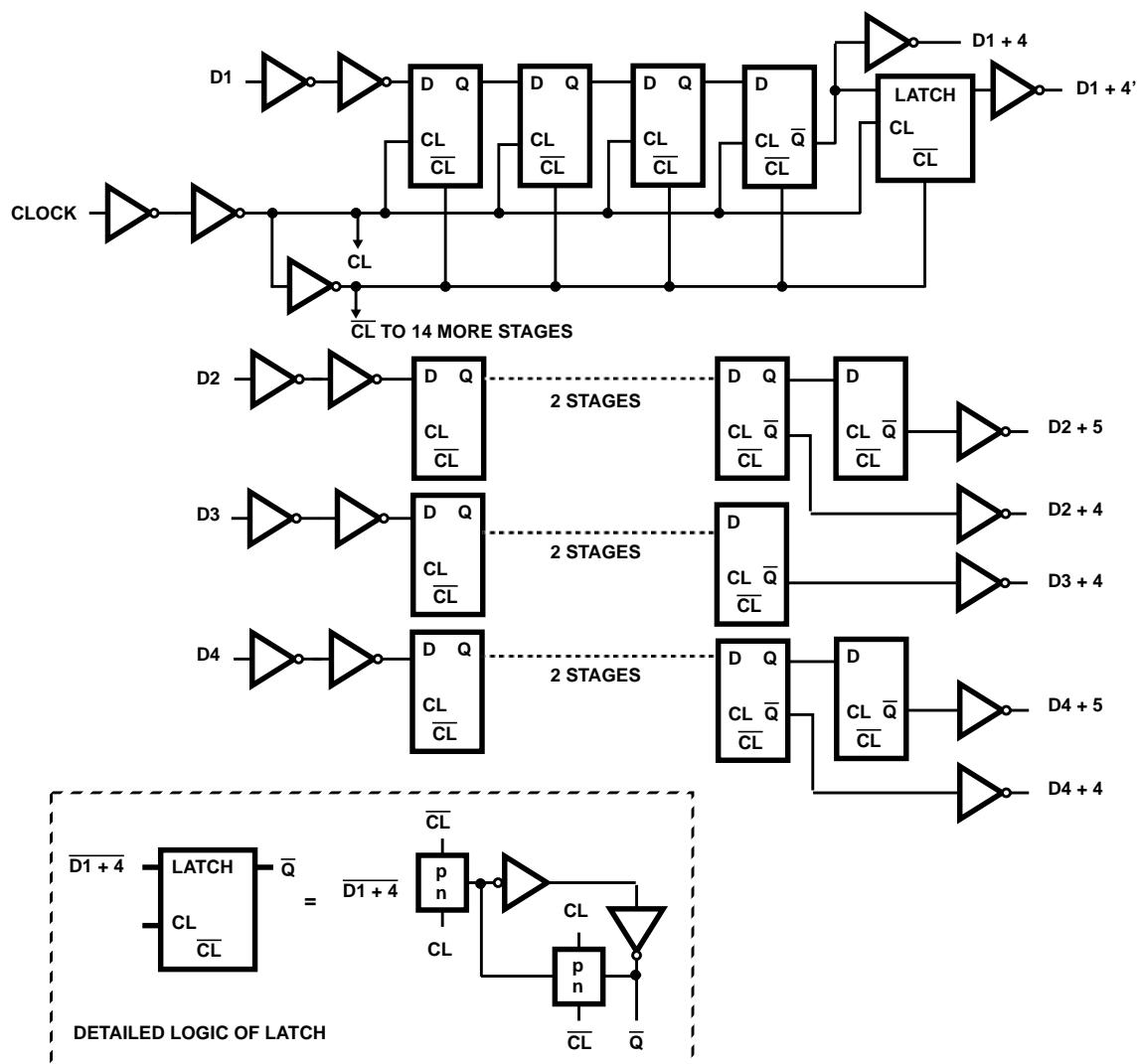
1 = HIGH

0 = LOW

NC = NO CHANGE

X = DON'T CARE

\* = LEVEL CHANGE



LOGIC DIAGRAM WITH DETAIL OF LATCH

## CD4006BMS

### Typical Performance Characteristics

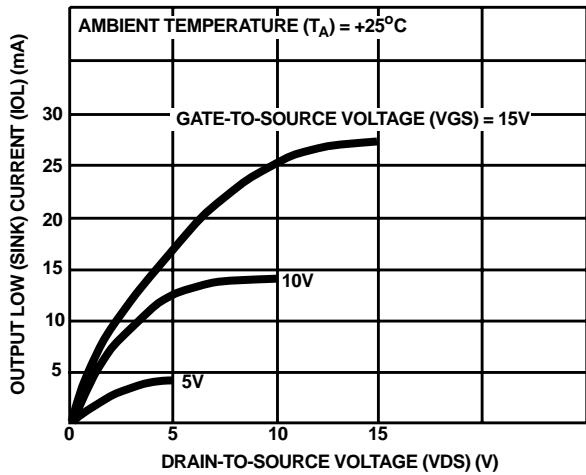


FIGURE 1. TYPICAL OUTPUT LOW (SINK) CURRENT CHARACTERISTICS

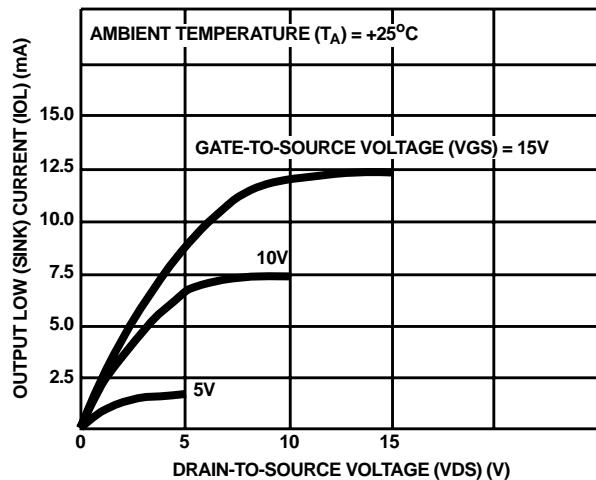


FIGURE 2. MINIMUM OUTPUT LOW (SINK) CURRENT CHARACTERISTICS

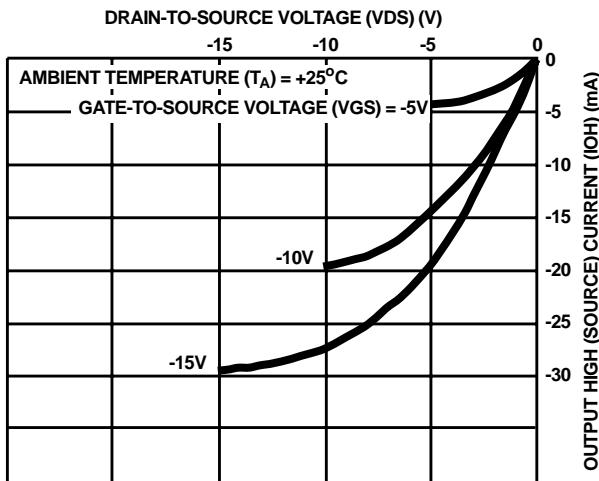


FIGURE 3. TYPICAL OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

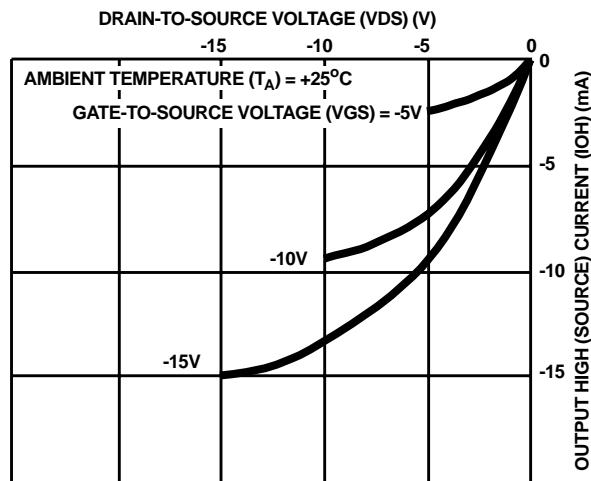


FIGURE 4. MINIMUM OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

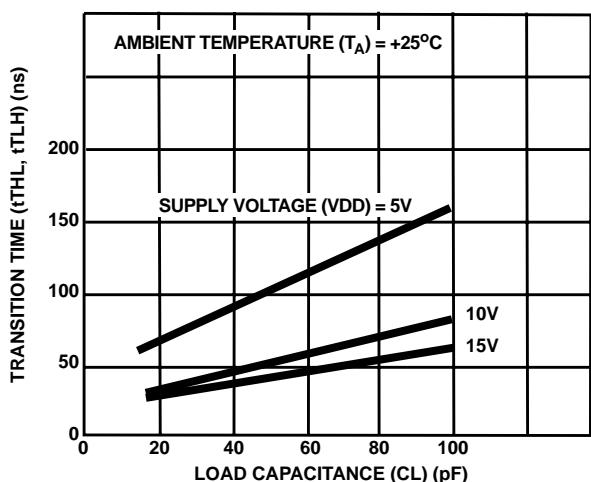


FIGURE 5. TYPICAL TRANSITION TIME AS A FUNCTION OF LOAD CAPACITANCE

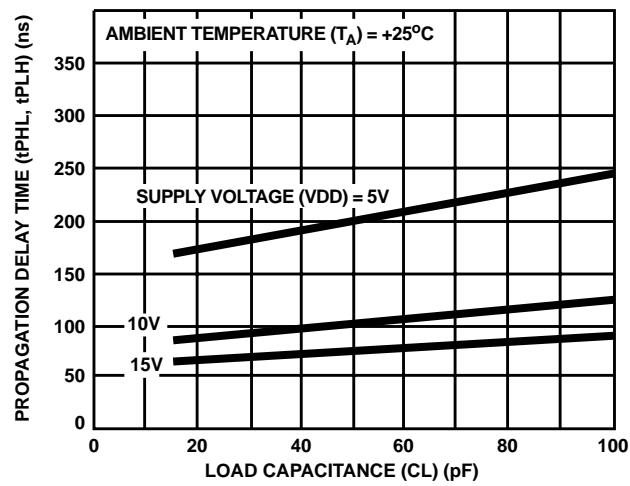


FIGURE 6. TYPICAL PROPAGATION DELAY TIME AS A FUNCTION OF LOAD CAPACITANCE

## CD4006BMS

### Typical Performance Characteristics (Continued)

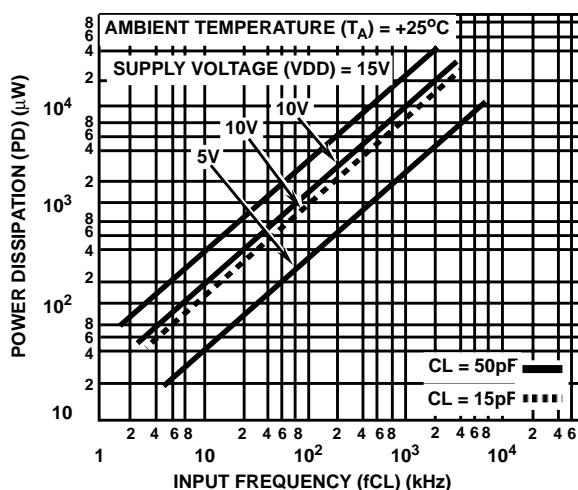
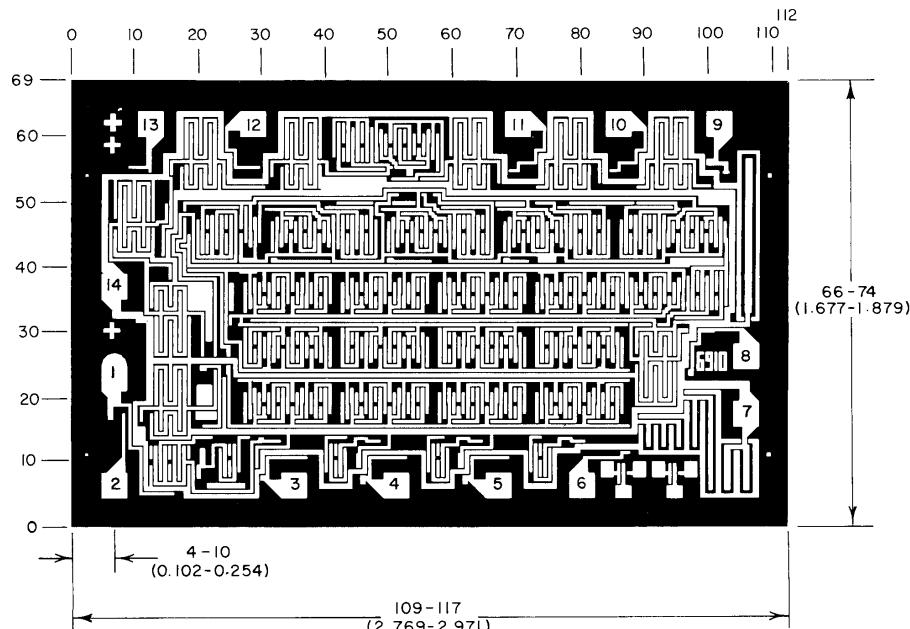


FIGURE 7. TYPICAL DYNAMIC POWER DISSIPATION AS A FUNCTION OF CLOCK FREQUENCY

### Chip Dimensions and Pad Layout



Dimensions in parentheses are in millimeters  
and are derived from the basic inch dimensions  
as indicated. Grid graduations are in mils (10<sup>-3</sup> inch)

**METALLIZATION:** Thickness: 11kÅ - 14kÅ, AL.

**PASSIVATION:** 10.4kÅ - 15.6kÅ, Silane

**BOND PADS:** 0.004 inches X 0.004 inches MIN

**DIE THICKNESS:** 0.0198 inches - 0.0218 inches

All Intersil semiconductor products are manufactured, assembled and tested under **ISO9000** quality systems certification.

Intersil products are sold by description only. Intersil Corporation reserves the right to make changes in circuit design and/or specifications at any time without notice. Accordingly, the reader is cautioned to verify that data sheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.